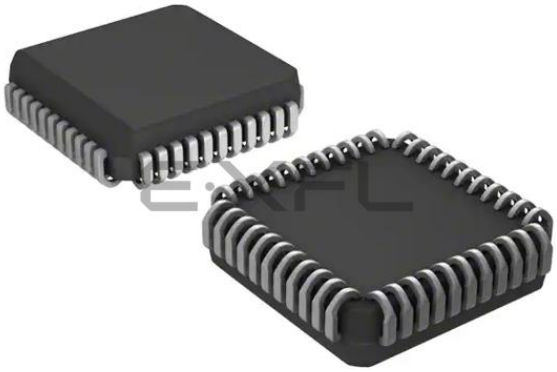

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Understanding Embedded - CPLDs (Complex Programmable Logic Devices)

Embedded - CPLDs, or Complex Programmable Logic Devices, are highly versatile digital logic devices used in electronic systems. These programmable components are designed to perform complex logical operations and can be customized for specific applications. Unlike fixed-function ICs, CPLDs offer the flexibility to reprogram their configuration, making them an ideal choice for various embedded systems. They consist of a set of logic gates and programmable interconnects, allowing designers to implement complex logic circuits without needing custom hardware.

Applications of Embedded - CPLDs

Details	
Product Status	Obsolete
Programmable Type	In System Programmable
Delay Time tpd(1) Max	4.5 ns
Voltage Supply - Internal	3V ~ 3.6V
Number of Logic Elements/Blocks	2
Number of Macrocells	32
Number of Gates	600
Number of I/O	34
Operating Temperature	0°C ~ 70°C (TA)
Mounting Type	Surface Mount
Package / Case	44-LCC (J-Lead)
Supplier Device Package	44-PLCC (16.59x16.59)
Purchase URL	https://www.e-xfl.com/product-detail/intel/epm3032alc44-4

Table 2. MAX 3000A Speed Grades

Device	Speed Grade				
	–4	–5	–6	–7	–10
EPM3032A	✓			✓	✓
EPM3064A	✓			✓	✓
EPM3128A		✓		✓	✓
EPM3256A				✓	✓
EPM3512A				✓	✓

The MAX 3000A architecture supports 100% transistor-to-transistor logic (TTL) emulation and high–density small-scale integration (SSI), medium-scale integration (MSI), and large-scale integration (LSI) logic functions. The MAX 3000A architecture easily integrates multiple devices ranging from PALs, GALs, and 22V10s to MACH and pLSI devices. MAX 3000A devices are available in a wide range of packages, including PLCC, PQFP, and TQFP packages. See Table 3.

Table 3. MAX 3000A Maximum User I/O Pins *Note (1)*

Device	44–Pin PLCC	44–Pin TQFP	100–Pin TQFP	144–Pin TQFP	208–Pin PQFP	256-Pin FineLine BGA
EPM3032A	34	34				
EPM3064A	34	34	66			
EPM3128A			80	96		98
EPM3256A				116	158	161
EPM3512A					172	208

Note:
(1) When the IEEE Std. 1149.1 (JTAG) interface is used for in–system programming or boundary–scan testing, four I/O pins become JTAG pins.

MAX 3000A devices use CMOS EEPROM cells to implement logic functions. The user–configurable MAX 3000A architecture accommodates a variety of independent combinatorial and sequential logic functions. The devices can be reprogrammed for quick and efficient iterations during design development and debugging cycles, and can be programmed and erased up to 100 times.

MAX 3000A devices contain 32 to 512 macrocells, combined into groups of 16 macrocells called logic array blocks (LABs). Each macrocell has a programmable–AND/fixed–OR array and a configurable register with independently programmable clock, clock enable, clear, and preset functions. To build complex logic functions, each macrocell can be supplemented with shareable expander and high–speed parallel expander product terms to provide up to 32 product terms per macrocell.

MAX 3000A devices provide programmable speed/power optimization. Speed–critical portions of a design can run at high speed/full power, while the remaining portions run at reduced speed/low power. This speed/power optimization feature enables the designer to configure one or more macrocells to operate at 50% or lower power while adding only a nominal timing delay. MAX 3000A devices also provide an option that reduces the slew rate of the output buffers, minimizing noise transients when non–speed–critical signals are switching. The output drivers of all MAX 3000A devices can be set for 2.5 V or 3.3 V, and all input pins are 2.5–V, 3.3–V, and 5.0-V tolerant, allowing MAX 3000A devices to be used in mixed–voltage systems.

MAX 3000A devices are supported by Altera development systems, which are integrated packages that offer schematic, text—including VHDL, Verilog HDL, and the Altera Hardware Description Language (AHDL)—and waveform design entry, compilation and logic synthesis, simulation and timing analysis, and device programming. The software provides EDIF 2 0 0 and 3 0 0, LPM, VHDL, Verilog HDL, and other interfaces for additional design entry and simulation support from other industry–standard PC– and UNIX–workstation–based EDA tools. The software runs on Windows–based PCs, as well as Sun SPARCstation, and HP 9000 Series 700/800 workstations.

For more information on development tools, see the *MAX+PLUS II Programmable Logic Development System & Software Data Sheet* and the *Quartus Programmable Logic Development System & Software Data Sheet*.

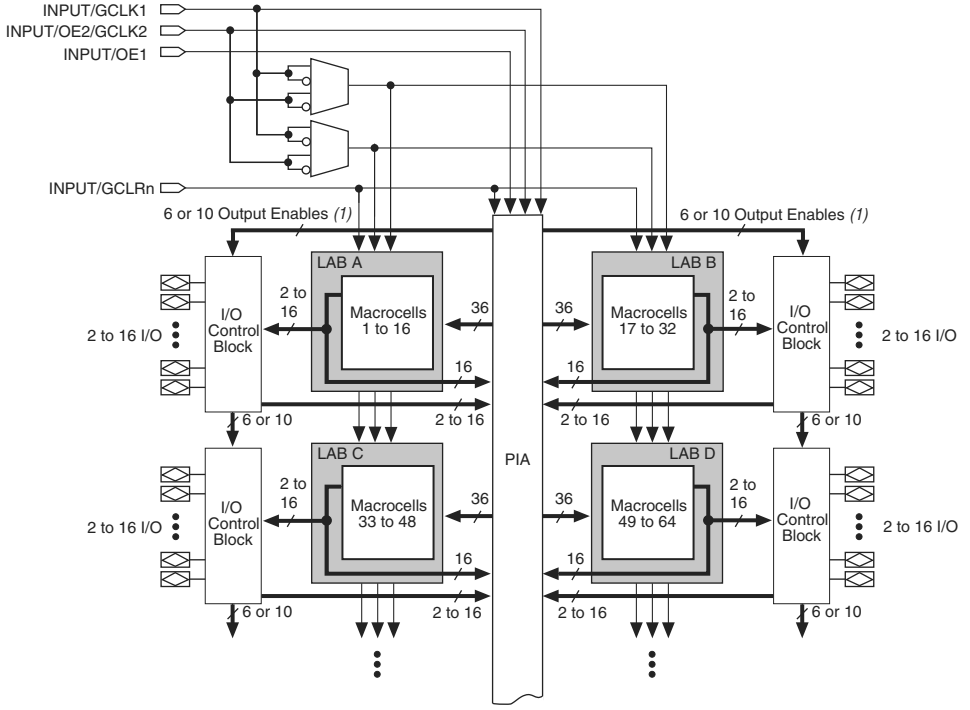
Functional Description

The MAX 3000A architecture includes the following elements:

- Logic array blocks (LABs)
- Macrocells
- Expander product terms (shareable and parallel)
- Programmable interconnect array (PIA)
- I/O control blocks

The MAX 3000A architecture includes four dedicated inputs that can be used as general–purpose inputs or as high–speed, global control signals (clock, clear, and two output enable signals) for each macrocell and I/O pin. Figure 1 shows the architecture of MAX 3000A devices.

Figure 1. MAX 3000A Device Block Diagram



Note:

(1) EPM3032A, EPM3064A, EPM3128A, and EPM3256A devices have six output enables. EPM3512A devices have 10 output enables.

Logic Array Blocks

The MAX 3000A device architecture is based on the linking of high–performance LABs. LABs consist of 16–macrocell arrays, as shown in Figure 1. Multiple LABs are linked together via the PIA, a global bus that is fed by all dedicated input pins, I/O pins, and macrocells.

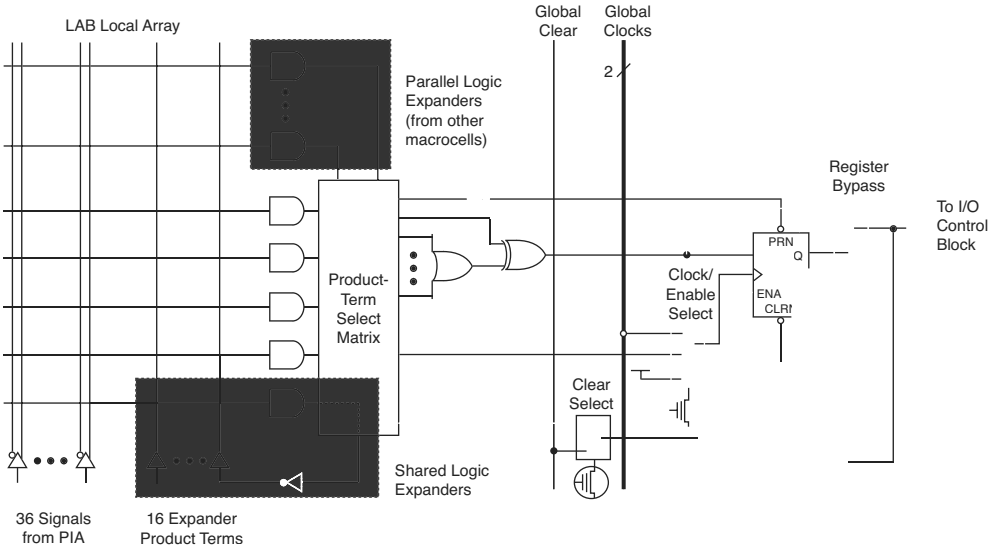
Each LAB is fed by the following signals:

- 36 signals from the PIA that are used for general logic inputs
- Global controls that are used for secondary register functions

Macrocells

MAX 3000A macrocells can be individually configured for either sequential or combinatorial logic operation. Macrocells consist of three functional blocks: logic array, product–term select matrix, and programmable register. Figure 2 shows a MAX 3000A macrocell.

Figure 2. MAX 3000A Macrocell



Combinatorial logic is implemented in the logic array, which provides five product terms per macrocell. The product–term select matrix allocates these product terms for use as either primary logic inputs (to the OR and XOR gates) to implement combinatorial functions, or as secondary inputs to the macrocell's register preset, clock, and clock enable control functions.

Two kinds of expander product terms ("expanders") are available to supplement macrocell logic resources:

- Shareable expanders, which are inverted product terms that are fed back into the logic array
- Parallel expanders, which are product terms borrowed from adjacent macrocells

The Altera development system automatically optimizes product–term allocation according to the logic requirements of the design.

For registered functions, each macrocell flipflop can be individually programmed to implement D, T, JK, or SR operation with programmable clock control. The flipflop can be bypassed for combinatorial operation. During design entry, the designer specifies the desired flipflop type; the Altera development system software then selects the most efficient flipflop operation for each registered function to optimize resource utilization.

Each programmable register can be clocked in three different modes:

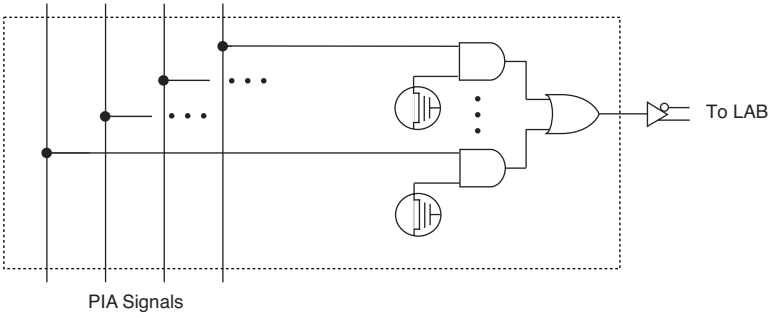
- Global clock signal mode, which achieves the fastest clock–to–output performance.
- Global clock signal enabled by an active–high clock enable. A clock enable is generated by a product term. This mode provides an enable on each flipflop while still achieving the fast clock–to–output performance of the global clock.
- Array clock implemented with a product term. In this mode, the flipflop can be clocked by signals from buried macrocells or I/O pins.

Two global clock signals are available in MAX 3000A devices. As shown in Figure 1, these global clock signals can be the true or the complement of either of the two global clock pins, `GCLK1` or `GCLK2`.

Each register also supports asynchronous preset and clear functions. As shown in Figure 2, the product–term select matrix allocates product terms to control these operations. Although the product–term–driven preset and clear from the register are active high, active–low control can be obtained by inverting the signal within the logic array. In addition, each register clear function can be individually driven by the active–low dedicated global clear pin (`GCLRn`).

All registers are cleared upon power-up. By default, all registered outputs drive low when the device is powered up. You can set the registered outputs to drive high upon power-up through the Quartus® II software. Quartus II software uses the NOT Gate Push-Back method, which uses an additional macrocell to set the output high. To set this in the Quartus II software, go to the Assignment Editor and set the **Power-Up Level** assignment for the register to **High**.

Figure 5. MAX 3000A PIA Routing



While the routing delays of channel–based routing schemes in masked or FPGAs are cumulative, variable, and path–dependent, the MAX 3000A PIA has a predictable delay. The PIA makes a design's timing performance easy to predict.

I/O Control Blocks

The I/O control block allows each I/O pin to be individually configured for input, output, or bidirectional operation. All I/O pins have a tri–state buffer that is individually controlled by one of the global output enable signals or directly connected to ground or V_{CC}. Figure 6 shows the I/O control block for MAX 3000A devices. The I/O control block has 6 or 10 global output enable signals that are driven by the true or complement of two output enable signals, a subset of the I/O pins, or a subset of the I/O macrocells.

In–System Programmability

MAX 3000A devices can be programmed in–system via an industry–standard four–pin IEEE Std. 1149.1-1990 (JTAG) interface. In-system programmability (ISP) offers quick, efficient iterations during design development and debugging cycles. The MAX 3000A architecture internally generates the high programming voltages required to program its EEPROM cells, allowing in–system programming with only a single 3.3–V power supply. During in–system programming, the I/O pins are tri–stated and weakly pulled–up to eliminate board conflicts. The pull–up value is nominally 50 kΩ

MAX 3000A devices have an enhanced ISP algorithm for faster programming. These devices also offer an `ISP_Done` bit that ensures safe operation when in–system programming is interrupted. This `ISP_Done` bit, which is the last bit programmed, prevents all I/O pins from driving until the bit is programmed.

ISP simplifies the manufacturing flow by allowing devices to be mounted on a printed circuit board (PCB) with standard pick–and–place equipment before they are programmed. MAX 3000A devices can be programmed by downloading the information via in–circuit testers, embedded processors, the MasterBlaster communications cable, the ByteBlasterMV parallel port download cable, and the BitBlaster serial download cable. Programming the devices after they are placed on the board eliminates lead damage on high–pin–count packages (e.g., QFP packages) due to device handling. MAX 3000A devices can be reprogrammed after a system has already shipped to the field. For example, product upgrades can be performed in the field via software or modem.

The Jam STAPL programming and test language can be used to program MAX 3000A devices with in–circuit testers, PCs, or embedded processors.

For more information on using the Jam STAPL programming and test language, see *Application Note 88 (Using the Jam Language for ISP & ICR via an Embedded Processor)*, *Application Note 122 (Using Jam STAPL for ISP & ICR via an Embedded Processor)* and *AN 111 (Embedded Programming Using the 8051 and Jam Byte-Code)*.

The ISP circuitry in MAX 3000A devices is compliant with the IEEE Std. 1532 specification. The IEEE Std. 1532 is a standard developed to allow concurrent ISP between multiple PLD vendors.

Programming Sequence

During in-system programming, instructions, addresses, and data are shifted into the MAX 3000A device through the TDI input pin. Data is shifted out through the TDO output pin and compared against the expected data.

Programming a pattern into the device requires the following six ISP stages. A stand-alone verification of a programmed pattern involves only stages 1, 2, 5, and 6.

1. *Enter ISP*. The enter ISP stage ensures that the I/O pins transition smoothly from user mode to ISP mode. The enter ISP stage requires 1 ms.

2. *Check ID*. Before any program or verify process, the silicon ID is checked. The time required to read this silicon ID is relatively small compared to the overall programming time.

3. *Bulk Erase*. Erasing the device in-system involves shifting in the instructions to erase the device and applying one erase pulse of 100 ms.

4. *Program*. Programming the device in-system involves shifting in the address and data and then applying the programming pulse to program the EEPROM cells. This process is repeated for each EEPROM address.

5. *Verify*. Verifying an Altera device in-system involves shifting in addresses, applying the read pulse to verify the EEPROM cells, and shifting out the data for comparison. This process is repeated for each EEPROM address.

6. *Exit ISP*. An exit ISP stage ensures that the I/O pins transition smoothly from ISP mode to user mode. The exit ISP stage requires 1 ms.

Programming Times

The time required to implement each of the six programming stages can be broken into the following two elements:

- A pulse time to erase, program, or read the EEPROM cells.
- A shifting time based on the test clock (TCK) frequency and the number of TCK cycles to shift instructions, address, and data into the device.

The instruction register length of MAX 3000A devices is 10 bits. The IDCODE and USERCODE register length is 32 bits. Tables 8 and 9 show the boundary–scan register length and device IDCODE information for MAX 3000A devices.

Table 8. MAX 3000A Boundary–Scan Register Length

Device	Boundary–Scan Register Length
EPM3032A	96
EPM3064A	192
EPM3128A	288
EPM3256A	480
EPM3512A	624

Table 9. 32–Bit MAX 3000A Device IDCODE Value *Note (1)*

Device	IDCODE (32 bits)			
	Version (4 Bits)	Part Number (16 Bits)	Manufacturer's Identity (11 Bits)	1 (1 Bit) *(2)*
EPM3032A	0001	0111 0000 0011 0010	00001101110	1
EPM3064A	0001	0111 0000 0110 0100	00001101110	1
EPM3128A	0001	0111 0001 0010 1000	00001101110	1
EPM3256A	0001	0111 0010 0101 0110	00001101110	1
EPM3512A	0001	0111 0101 0001 0010	00001101110	1

Notes:
(1) The most significant bit (MSB) is on the left.
(2) The least significant bit (LSB) for all JTAG IDCODEs is 1.

See *Application Note 39 (IEEE 1149.1 (JTAG) Boundary–Scan Testing in Altera Devices)* for more information on JTAG BST.

Programmable Speed/Power Control

MAX 3000A devices offer a power–saving mode that supports low-power operation across user–defined signal paths or the entire device. This feature allows total power dissipation to be reduced by 50% or more because most logic applications require only a small fraction of all gates to operate at maximum frequency.

The designer can program each individual macrocell in a MAX 3000A device for either high–speed or low–power operation. As a result, speed-critical paths in the design can run at high speed, while the remaining paths can operate at reduced power. Macrocells that run at low power incur a nominal timing delay adder (t_{LPA}) for the t_{LAD}, t_{LAC}, t_{IC}, t_{ACL}, t_{EN}, t_{CPPW} and t_{SEXP} parameters.

Output Configuration

MAX 3000A device outputs can be programmed to meet a variety of system–level requirements.

MultiVolt I/O Interface

The MAX 3000A device architecture supports the MultiVolt I/O interface feature, which allows MAX 3000A devices to connect to systems with differing supply voltages. MAX 3000A devices in all packages can be set for 2.5–V, 3.3–V, or 5.0–V I/O pin operation. These devices have one set of V_{CC} pins for internal operation and input buffers (VCCINT), and another set for I/O output drivers (VCCIO).

The VCCIO pins can be connected to either a 3.3–V or 2.5–V power supply, depending on the output requirements. When the VCCIO pins are connected to a 2.5–V power supply, the output levels are compatible with 2.5–V systems. When the VCCIO pins are connected to a 3.3–V power supply, the output high is at 3.3 V and is therefore compatible with 3.3-V or 5.0–V systems. Devices operating with V_{CCIO} levels lower than 3.0 V incur a nominally greater timing delay of t_{OD2} instead of t_{OD1}. Inputs can always be driven by 2.5–V, 3.3–V, or 5.0–V signals.

Table 11 summarizes the MAX 3000A MultiVolt I/O support.

Table 11. MAX 3000A MultiVolt I/O Support

V_{CCIO} Voltage	Input Signal (V)			Output Signal (V)		
	2.5	3.3	5.0	2.5	3.3	5.0
2.5	✓	✓	✓	✓		
3.3	✓	✓	✓	✓	✓	✓

Note:
(1) When V_{CCIO} is 3.3 V, a MAX 3000A device can drive a 2.5–V device that has 3.3–V tolerant inputs.

Tables 16 through 23 show EPM3032A, EPM3064A, EPM3128A, EPM3256A, and EPM3512A timing information.

Table 16. EPM3032A External Timing Parameters *Note (1)*

Symbol	Parameter	Conditions	Speed Grade						Unit
			–4		–7		–10		
			Min	Max	Min	Max	Min	Max	
t_{PD1}	Input to non–registered output	C1 = 35 pF *(2)*		4.5		7.5		10	ns
t_{PD2}	I/O input to non–registered output	C1 = 35 pF *(2)*		4.5		7.5		10	ns
t_{SU}	Global clock setup time	*(2)*	2.9		4.7		6.3		ns
t_{H}	Global clock hold time	*(2)*	0.0		0.0		0.0		ns
t_{CO1}	Global clock to output delay	C1 = 35 pF	1.0	3.0	1.0	5.0	1.0	6.7	ns
t_{CH}	Global clock high time		2.0		3.0		4.0		ns
t_{CL}	Global clock low time		2.0		3.0		4.0		ns
t_{ASU}	Array clock setup time	*(2)*	1.6		2.5		3.6		ns
t_{AH}	Array clock hold time	*(2)*	0.3		0.5		0.5		ns
t_{ACO1}	Array clock to output delay	C1 = 35 pF *(2)*	1.0	4.3	1.0	7.2	1.0	9.4	ns
t_{ACH}	Array clock high time		2.0		3.0		4.0		ns
t_{ACL}	Array clock low time		2.0		3.0		4.0		ns
t_{CPPW}	Minimum pulse width for clear and preset	*(3)*	2.0		3.0		4.0		ns
t_{CNT}	Minimum global clock period	*(2)*		4.4		7.2		9.7	ns
f_{CNT}	Maximum internal global clock frequency	*(2)*, *(4)*	227.3		138.9		103.1		MHz
t_{ACNT}	Minimum array clock period	*(2)*		4.4		7.2		9.7	ns
f_{ACNT}	Maximum internal array clock frequency	*(2)*, *(4)*	227.3		138.9		103.1		MHz

Table 17. EPM3032A Internal Timing Parameters (Part 1 of 2) *Note (1)*

Symbol	Parameter	Conditions	Speed Grade						Unit
			–4		–7		–10		
			Min	Max	Min	Max	Min	Max	
t_{IN}	Input pad and buffer delay			0.7		1.2		1.5	ns
t_{IO}	I/O input pad and buffer delay			0.7		1.2		1.5	ns
t_{SEXP}	Shared expander delay			1.9		3.1		4.0	ns
t_{PEXP}	Parallel expander delay			0.5		0.8		1.0	ns
t_{LAD}	Logic array delay			1.5		2.5		3.3	ns
t_{LAC}	Logic control array delay			0.6		1.0		1.2	ns
t_{IOE}	Internal output enable delay			0.0		0.0		0.0	ns
t_{OD1}	Output buffer and pad delay, slow slew rate = off V_{CCIO} = 3.3 V	C1 = 35 pF		0.8		1.3		1.8	ns
t_{OD2}	Output buffer and pad delay, slow slew rate = off V_{CCIO} = 2.5 V	C1 = 35 pF		1.3		1.8		2.3	ns
t_{OD3}	Output buffer and pad delay, slow slew rate = on V_{CCIO} = 2.5 V or 3.3 V	C1 = 35 pF		5.8		6.3		6.8	ns
t_{ZX1}	Output buffer enable delay, slow slew rate = off V_{CCIO} = 3.3 V	C1 = 35 pF		4.0		4.0		5.0	ns
t_{ZX2}	Output buffer enable delay, slow slew rate = off V_{CCIO} = 2.5 V	C1 = 35 pF		4.5		4.5		5.5	ns
t_{ZX3}	Output buffer enable delay, slow slew rate = on V_{CCIO} = 2.5 V or 3.3 V	C1 = 35 pF		9.0		9.0		10.0	ns
t_{XZ}	Output buffer disable delay	C1 = 5 pF		4.0		4.0		5.0	ns
t_{SU}	Register setup time		1.3		2.0		2.8		ns
t_{H}	Register hold time		0.6		1.0		1.3		ns
t_{RD}	Register delay			0.7		1.2		1.5	ns
t_{COMB}	Combinatorial delay			0.6		1.0		1.3	ns
t_{IC}	Array clock delay			1.2		2.0		2.5	ns
t_{EN}	Register enable time			0.6		1.0		1.2	ns
t_{GLOB}	Global control delay			0.8		1.3		1.9	ns
t_{PRE}	Register preset time			1.2		1.9		2.6	ns
t_{CLR}	Register clear time			1.2		1.9		2.6	ns

Table 17. EPM3032A Internal Timing Parameters (Part 2 of 2) *Note (1)*

Symbol	Parameter	Conditions	Speed Grade						Unit
			–4		–7		–10		
			Min	Max	Min	Max	Min	Max	
t_{PIA}	PIA delay	*(2)*		0.9		1.5		2.1	ns
t_{LPA}	Low–power adder	*(5)*		2.5		4.0		5.0	ns

Table 18. EPM3064A External Timing Parameters *Note (1)*

Symbol	Parameter	Conditions	Speed Grade						Unit
			–4		–7		–10		
			Min	Max	Min	Max	Min	Max	
t_{PD1}	Input to non–registered output	C1 = 35 pF *(2)*		4.5		7.5		10.0	ns
t_{PD2}	I/O input to non–registered output	C1 = 35 pF *(2)*		4.5		7.5		10.0	ns
t_{SU}	Global clock setup time	*(2)*	2.8		4.7		6.2		ns
t_{H}	Global clock hold time	*(2)*	0.0		0.0		0.0		ns
t_{CO1}	Global clock to output delay	C1 = 35 pF	1.0	3.1	1.0	5.1	1.0	7.0	ns
t_{CH}	Global clock high time		2.0		3.0		4.0		ns
t_{CL}	Global clock low time		2.0		3.0		4.0		ns
t_{ASU}	Array clock setup time	*(2)*	1.6		2.6		3.6		ns
t_{AH}	Array clock hold time	*(2)*	0.3		0.4		0.6		ns
t_{ACO1}	Array clock to output delay	C1 = 35 pF *(2)*	1.0	4.3	1.0	7.2	1.0	9.6	ns
t_{ACH}	Array clock high time		2.0		3.0		4.0		ns
t_{ACL}	Array clock low time		2.0		3.0		4.0		ns
t_{CPPW}	Minimum pulse width for clear and preset	*(3)*	2.0		3.0		4.0		ns
t_{CNT}	Minimum global clock period	*(2)*		4.5		7.4		10.0	ns
f_{CNT}	Maximum internal global clock frequency	*(2)*, *(4)*	222.2		135.1		100.0		MHz
t_{ACNT}	Minimum array clock period	*(2)*		4.5		7.4		10.0	ns
f_{ACNT}	Maximum internal array clock frequency	*(2)*, *(4)*	222.2		135.1		100.0		MHz

Table 19. EPM3064A Internal Timing Parameters (Part 1 of 2) *Note (1)*

Symbol	Parameter	Conditions	Speed Grade						Unit
			–4		–7		–10		
			Min	Max	Min	Max	Min	Max	
t_{IN}	Input pad and buffer delay			0.6		1.1		1.4	ns
t_{IO}	I/O input pad and buffer delay			0.6		1.1		1.4	ns
t_{SEXP}	Shared expander delay			1.8		3.0		3.9	ns
t_{PEXP}	Parallel expander delay			0.4		0.7		0.9	ns
t_{LAD}	Logic array delay			1.5		2.5		3.2	ns
t_{LAC}	Logic control array delay			0.6		1.0		1.2	ns
t_{IOE}	Internal output enable delay			0.0		0.0		0.0	ns
t_{OD1}	Output buffer and pad delay, slow slew rate = off V_{CCIO} = 3.3 V	C1 = 35 pF		0.8		1.3		1.8	ns
t_{OD2}	Output buffer and pad delay, slow slew rate = off V_{CCIO} = 2.5 V	C1 = 35 pF		1.3		1.8		2.3	ns
t_{OD3}	Output buffer and pad delay, slow slew rate = on V_{CCIO} = 2.5 V or 3.3 V	C1 = 35 pF		5.8		6.3		6.8	ns
t_{ZX1}	Output buffer enable delay, slow slew rate = off V_{CCIO} = 3.3 V	C1 = 35 pF		4.0		4.0		5.0	ns
t_{ZX2}	Output buffer enable delay, slow slew rate = off V_{CCIO} = 2.5 V	C1 = 35 pF		4.5		4.5		5.5	ns
t_{ZX3}	Output buffer enable delay, slow slew rate = on V_{CCIO} = 2.5 V or 3.3 V	C1 = 35 pF		9.0		9.0		10.0	ns
t_{XZ}	Output buffer disable delay	C1 = 5 pF		4.0		4.0		5.0	ns
t_{SU}	Register setup time		1.3		2.0		2.9		ns
t_{H}	Register hold time		0.6		1.0		1.3		ns
t_{RD}	Register delay			0.7		1.2		1.6	ns
t_{COMB}	Combinatorial delay			0.6		0.9		1.3	ns
t_{IC}	Array clock delay			1.2		1.9		2.5	ns
t_{EN}	Register enable time			0.6		1.0		1.2	ns
t_{GLOB}	Global control delay			1.0		1.5		2.2	ns
t_{PRE}	Register preset time			1.3		2.1		2.9	ns

Table 20. EPM3128A External Timing Parameters *Note (1)*

Symbol	Parameter	Conditions	Speed Grade						Unit
			–5		–7		–10		
			Min	Max	Min	Max	Min	Max	
f_{ACNT}	Maximum internal array clock frequency	*(2), (4)*	192.3		129.9		98.0		MHz

Table 21. EPM3128A Internal Timing Parameters (Part 1 of 2) *Note (1)*

Symbol	Parameter	Conditions	Speed Grade						Unit
			–5		–7		–10		
			Min	Max	Min	Max	Min	Max	
t_{IN}	Input pad and buffer delay			0.7		1.0		1.4	ns
t_{IO}	I/O input pad and buffer delay			0.7		1.0		1.4	ns
t_{SEXP}	Shared expander delay			2.0		2.9		3.8	ns
t_{PEXP}	Parallel expander delay			0.4		0.7		0.9	ns
t_{LAD}	Logic array delay			1.6		2.4		3.1	ns
t_{LAC}	Logic control array delay			0.7		1.0		1.3	ns
t_{IOE}	Internal output enable delay			0.0		0.0		0.0	ns
t_{OD1}	Output buffer and pad delay, slow slew rate = off V_{CCIO} = 3.3 V	C1 = 35 pF		0.8		1.2		1.6	ns
t_{OD2}	Output buffer and pad delay, slow slew rate = off V_{CCIO} = 2.5 V	C1 = 35 pF		1.3		1.7		2.1	ns
t_{OD3}	Output buffer and pad delay, slow slew rate = on V_{CCIO} = 2.5 V or 3.3 V	C1 = 35 pF		5.8		6.2		6.6	ns
t_{ZX1}	Output buffer enable delay, slow slew rate = off V_{CCIO} = 3.3 V	C1 = 35 pF		4.0		4.0		5.0	ns
t_{ZX2}	Output buffer enable delay, slow slew rate = off V_{CCIO} = 2.5 V	C1 = 35 pF		4.5		4.5		5.5	ns
t_{ZX3}	Output buffer enable delay, slow slew rate = on V_{CCIO} = 2.5 V or 3.3 V	C1 = 35 pF		9.0		9.0		10.0	ns
t_{XZ}	Output buffer disable delay	C1 = 5 pF		4.0		4.0		5.0	ns

Table 23. EPM3256A Internal Timing Parameters (Part 2 of 2) *Note (1)*

Symbol	Parameter	Conditions	Speed Grade				Unit
			–7		–10		
			Min	Max	Min	Max	
t_{ZX3}	Output buffer enable delay, slow slew rate = on V_{CCIO} = 2.5 V or 3.3 V	C1 = 35 pF		9.0		10.0	ns
t_{XZ}	Output buffer disable delay	C1 = 5 pF		4.0		5.0	ns
t_{SU}	Register setup time		2.1		2.9		ns
t_{H}	Register hold time		0.9		1.2		ns
t_{RD}	Register delay			1.2		1.6	ns
t_{COMB}	Combinatorial delay			0.8		1.2	ns
t_{IC}	Array clock delay			1.6		2.1	ns
t_{EN}	Register enable time			1.0		1.3	ns
t_{GLOB}	Global control delay			1.5		2.0	ns
t_{PRE}	Register preset time			2.3		3.0	ns
t_{CLR}	Register clear time			2.3		3.0	ns
t_{PIA}	PIA delay	*(2)*		2.4		3.2	ns
t_{LPA}	Low–power adder	*(5)*		4.0		5.0	ns

Table 24. EPM3512A External Timing Parameters *Note (1)*

Symbol	Parameter	Conditions	Speed Grade				Unit
			-7		-10		
			Min	Max	Min	Max	
t_{PD1}	Input to non-registered output	C1 = 35 pF *(2)*		7.5		10.0	ns
t_{PD2}	I/O input to non-registered output	C1 = 35 pF *(2)*		7.5		10.0	ns
t_{SU}	Global clock setup time	*(2)*	5.6		7.6		ns
t_{H}	Global clock hold time	*(2)*	0.0		0.0		ns
t_{FSU}	Global clock setup time of fast input		3.0		3.0		ns
t_{FH}	Global clock hold time of fast input		0.0		0.0		ns
t_{CO1}	Global clock to output delay	C1 = 35 pF	1.0	4.7	1.0	6.3	ns
t_{CH}	Global clock high time		3.0		4.0		ns
t_{CL}	Global clock low time		3.0		4.0		ns
t_{ASU}	Array clock setup time	*(2)*	2.5		3.5		ns

Table 24. EPM3512A External Timing Parameters *Note (1)*

Symbol	Parameter	Conditions	Speed Grade				Unit
			-7		-10		
			Min	Max	Min	Max	
t_{AH}	Array clock hold time	*(2)*	0.2		0.3		ns
t_{ACO1}	Array clock to output delay	C1 = 35 pF *(2)*	1.0	7.8	1.0	10.4	ns
t_{ACH}	Array clock high time		3.0		4.0		ns
t_{ACL}	Array clock low time		3.0		4.0		ns
t_{CPPW}	Minimum pulse width for clear and preset	*(3)*	3.0		4.0		ns
t_{CNT}	Minimum global clock period	*(2)*		8.6		11.5	ns
f_{CNT}	Maximum internal global clock frequency	*(2)*, *(4)*	116.3		87.0		MHz
t_{ACNT}	Minimum array clock period	*(2)*		8.6		11.5	ns
f_{ACNT}	Maximum internal array clock frequency	*(2)*, *(4)*	116.3		87.0		MHz

Table 25. EPM3512A Internal Timing Parameters (Part 1 of 2) *Note (1)*

Symbol	Parameter	Conditions	Speed Grade				Unit
			-7		-10		
			Min	Max	Min	Max	
t_{IN}	Input pad and buffer delay			0.7		0.9	ns
t_{IO}	I/O input pad and buffer delay			0.7		0.9	ns
t_{FIN}	Fast input delay			3.1		3.6	ns
t_{SEXP}	Shared expander delay			2.7		3.5	ns
t_{PEXP}	Parallel expander delay			0.4		0.5	ns
t_{LAD}	Logic array delay			2.2		2.8	ns
t_{LAC}	Logic control array delay			1.0		1.3	ns
t_{IOE}	Internal output enable delay			0.0		0.0	ns
t_{OD1}	Output buffer and pad delay, slow slew rate = off V_{CCIO} = 3.3 V	C1 = 35 pF		1.0		1.5	ns
t_{OD2}	Output buffer and pad delay, slow slew rate = off V_{CCIO} = 2.5 V	C1 = 35 pF		1.5		2.0	ns

Figure 15. 100–Pin TQFP Package Pin–Out Diagram

Package outline not drawn to scale.

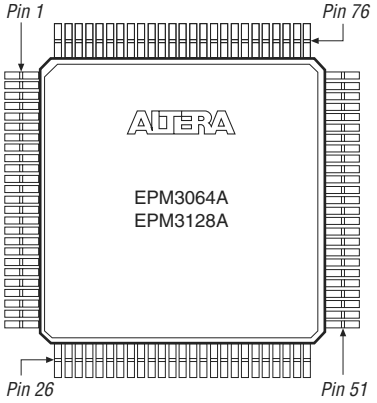


Figure 16. 144–Pin TQFP Package Pin–Out Diagram

Package outline not drawn to scale.

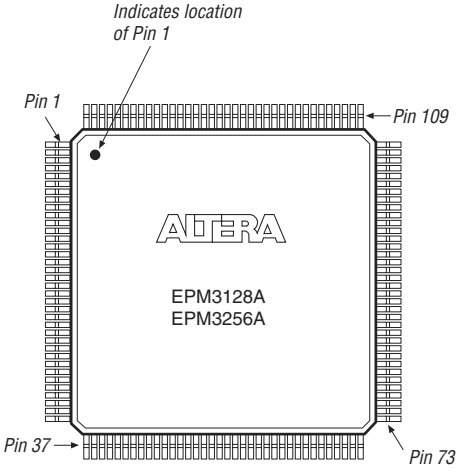
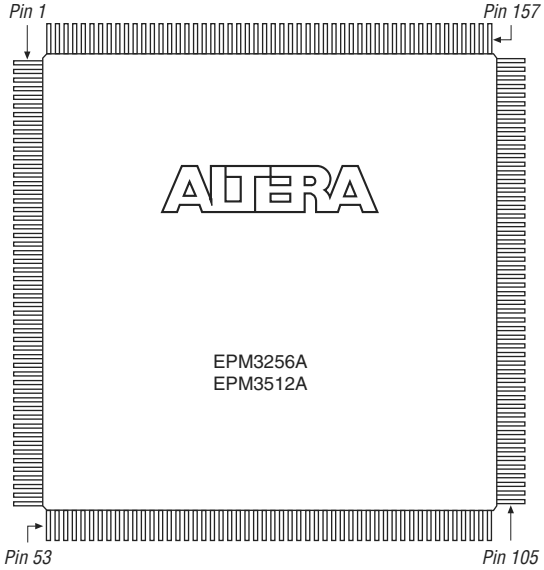


Figure 17. 208–Pin PQFP Package Pin–Out Diagram

Package outline not drawn to scale.



Version 3.3

The following changes were made in the *MAX 3000A Programmable Logic Device Data Sheet* version 3.3:

- Updated Tables 3, 13, and 26.
- Added Tables 4 through 6.
- Updated Figures 12 and 13.
- Added "Programming Sequence" on page 14 and "Programming Times" on page 14

Version 3.2

The following change were made in the *MAX 3000A Programmable Logic Device Data Sheet* version 3.2:

- Updated the EPM3512 I_{CC} versus frequency graph in Figure 13.

Version 3.1

The following changes were made in the *MAX 3000A Programmable Logic Device Data Sheet* version 3.1:

- Updated timing information in Table 1 for the EPM3256A device.
- Updated *Note (10)* of Table 15.

Version 3.0

The following changes were made in the *MAX 3000A Programmable Logic Device Data Sheet* version 3.0:

- Added EPM3512A device.
- Updated Tables 2 and 3.

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